

Ultra Low Noise Voltage Controlled Crystal Oscillator, General Specification (rev1)

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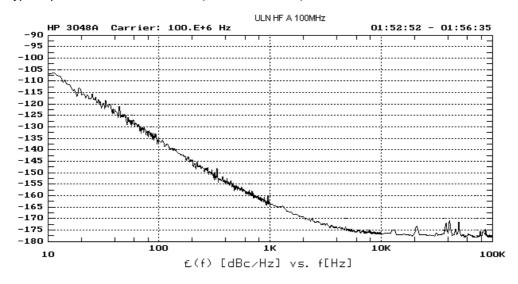


Ultra Low Noise Voltage Controlled Crystal Oscillator,
General Specification (rev1)

December 5th, 2007

Features

- Ultra Low Noise (ULN), Voltage Controlled, Crystal Oscillator (VC)XO
- Frequency range: 80 to 125 MHz
- Ultra low phase noise @ 100 MHz : 158 dBc/Hz @ 1 kHz offset
 - 174 dBc/Hz @ 10 kHz offset (noise floor)
- Operating temperature range : [-40 +85 ℃]
- Airborne environment
- 7-pin machined package with inner shock absorbers + SMA connector for the frequency output
- Typical phase noise @ 100 MHz (static conditions):



Applications

Airborne military equipment

Radar & Telecom

Environmental conditions

Parameters	Unit	Minimum	Typical	Maximum		
Operating temperature range	℃	- 40		+ 85		
Storage temperature range	℃	– 55		+ 125		
Relative humidity		Up to 100% at Ta = 0 ℃ to 85 ℃ without conden As per MIL-STD-810, Issue F (cat 5)				
Vibration, random						
Vibration, sine		As per	nethod 519.5 procedure IV			
Acceleration		As per MIL-STD-810, method 513.5 procedures I,II and III				
Shock (half sine)		As per MIL-STD-810, method 516.5 procedure I				



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Mechanical characteristics

[2.17] = 55 =

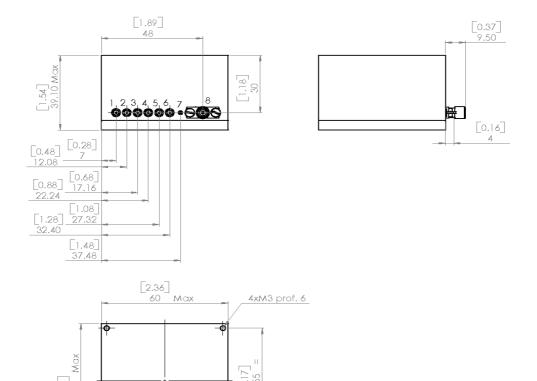


Figure 1 : Oscillator outline

Pin number	Name	Function			
1	Vcc oven	Supply voltage of oven			
2	2 Ground oven Ground of oven				
3	Oven alarm	Oven alarm			
4	Vcc RF	Supply voltage			
5	Vc	Electrical & mechanical ground			
6	Vref	Reference voltage			
7	Ground, case	Ground of RF			
8	SF	Output signal			

Table 1: Pin description



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Performance Characteristics

Electrical Parameters	Unit	Minimum	Typical	Maximum		
Frequency output (SMA Connector)						
Nominal frequency range	MHz	80	100	125		
Output level (50 Ω load)	dBm	11	13	15		
Output VSWR (Fo ± 1.5 MHz)	-			2:1		
Harmonics level	dBc			- 30		
Spurious (offset > 50 Hz)	dBc			- 70		
Phase noise in static conditions @ 100 MHz	Phase noise in static conditions @ 100 MHz					
@ 10 Hz offset	dBc/Hz		-105	- 100		
@ 100 Hz offset	dBc/Hz		-135	- 130		
@ 1 kHz offset	dBc/Hz		-163	- 158		
@ 10 kHz offset or greater	dBc/Hz		-176	- 174		
Phase noise in static conditions @ 120 MHz				•		
@ 10 Hz offset	dBc/Hz			- 93		
@ 100 Hz offset	dBc/Hz			- 123		
@ 1 kHz offset	dBc/Hz			- 155		
@ 10 kHz offset or greater	dBc/Hz			- 172		
g-sensitivity						
@ 25 Hz offset (resonance)	/g			2.5 10 ⁻⁹		
@ 100 Hz offset	/g			4.5 10 ⁻¹¹		
@ 1 kHz offset	/g			2.5 10 ⁻¹²		
Free running mode (Vctrl pin NC)						
Initial setting	ppm			± 3		
Stability vs. temperature	ppm			± 30		
Stability vs. 5 % supply voltage variation	ppm			± 0.1		
Stability vs. 10 % load variation	ppm			± 0.1		
Aging over first year	ppm			± 0.5		
Aging over 10 year	ppm			± 2		
Retrace	ppm			± 5		
Supply voltage (Vcc pin)						
Voltage range	V _{DC}	14.5	15	15.5		
Supply current @ 25 ℃	mA			50		



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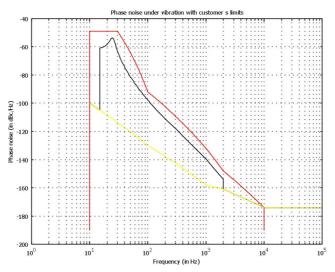


Figure 2 : Phase noise curves @ 100 MHz

Above is represented in yellow, the theoretical curve of the phase noise in static conditions and in black the phase noise in dynamic conditions.

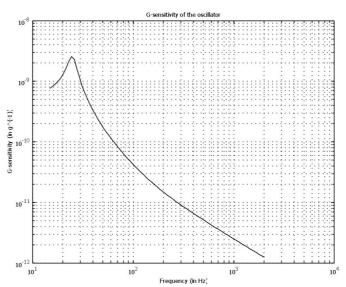


Figure 3: G-sensitivity of the oscillator

Above is represented the g-sensitivity of the oscillator